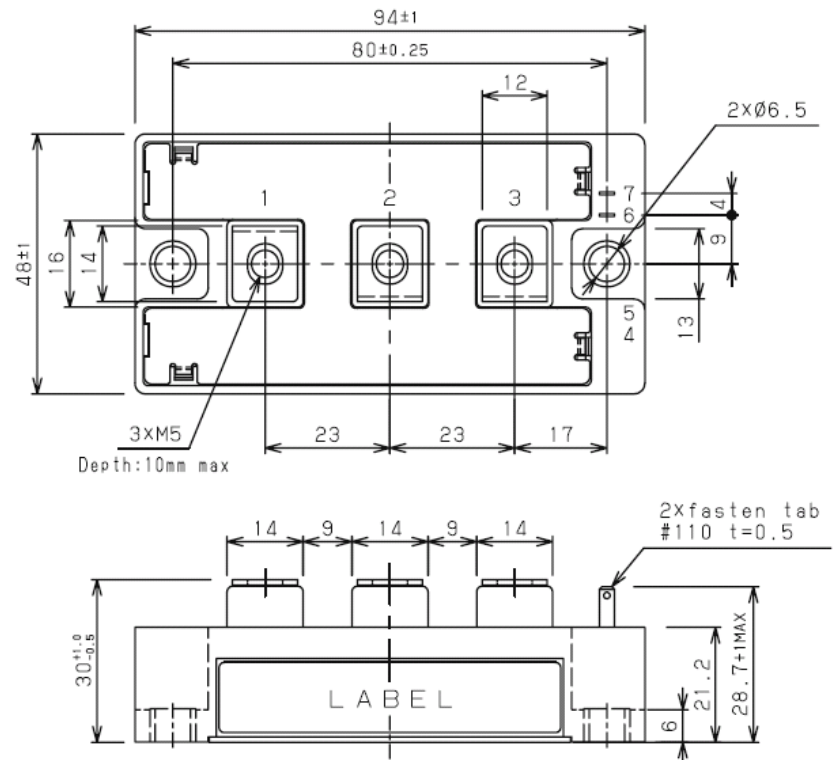
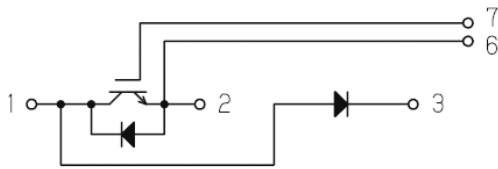


□ 回路図 : *CIRCUIT*

□ 概略図 : *SCHEMATIC DIAGRAM*

Dimension: [mm]



□ 最大定格 : *MAXIMUM RATINGS* (at $T_c=25^{\circ}\text{C}$ unless otherwise specified)

Item		Symbol	Condition	Rated Value	Unit
IGBT	コレクタ・エミッタ間電圧 Collector-Emitter Voltage	V _{CES}	G-E Short	1200	V
	ゲート・エミッタ間電圧 Gate-Emitter Voltage	V _{GES}	C-E Short	±20	V
	コレクタ電流 Collector Current	I _C	DC T _c =85℃	200	A
		I _{CP}	Pulse ≤ 1ms	400	
	コレクタ損失 Collector Power Dissipation	P _C	T _j =175℃	1153	W
T _j =150℃			961		
FWD	繰り返しピーク逆電圧 Repetitive peak reverse voltage	V _{RRM}		1200	V
	順電流 Forward Current	I _F		200	A
		I _{FM}	Pulse ≤ 1ms	400	
最大接合温度 Maximum Junction Temperature		T _{JMAX}	瞬時動作(過負荷) Instantaneous Overload	175	℃
接合温度範囲 Junction Temperature Range		T _j		-40~+150	℃
保存温度範囲 Storage Temperature Range		T _{stg}		-40~+125	℃
絶縁耐圧 Isolation Voltage		V _{ISO}	Terminal to Base AC, 1minute	2,500	V (RMS)
締め付けトルク Mounting Torque	Module Base to Heatsink	F _{tor}	M6	3	N・m
	Busbar to Main Terminal		M5	2	

□ 電 気 的 特 性 : **ELECTRICAL CHARACTERISTICS** (at $T_J=25^\circ\text{C}$ unless otherwise specified)

Characteristic			Symbol	Test Condition		Min.	Typ.	Max.	Unit
IGBT	コレクタ遮断電流 Collector-Emitter Cut-Off Current		ICES	VCE= 1200V,VGE= 0V		—	—	1.0	mA
	ゲート漏れ電流 Gate-Emitter Leakage Current		IGES	VGE= ±20V,VCE= 0V		—	—	1.0	μA
	コレクタ・エミッタ間飽和電圧 Collector-Emitter Saturation Voltage		VCE(sat.)	Ic= 200A,VGE= 15V (chip level)	TJ=25℃	—	1.50	2.00	V
					TJ=125℃	—	1.70	—	
					TJ=150℃	—	1.80	—	
	ゲートしきい値電圧 Gate-Emitter Threshold Voltage		VGE(th.)	VCE= 10V,Ic= 6.7mA		4.8	—	7.0	V
	入力容量 Input Capacitance		Cies	VCE= 25V,VGE= 0V,f= 1MHz		—	19.0	—	nF
	出力容量 Output Capacitance		Coes			—	0.56	—	
	帰還容量 Reverse Transfer Capacitance		Cres			—	0.45	—	
	ゲート電荷量 Gate Charge		Qg	Vcc=600V, Ic=200A, VGE=-15~+15V		—	2200	—	nC
スイッチング時間 Switching Time	上昇時間 Rise Time	tr	VCC= 600V LS=38nH Ic= 200A Inductive Load Rg= 3.6Ω VGE= ±15V Tj= 150℃		—	60	—	ns	
	ターンオン遅延時間 Turn-on Delay Time	td(on)			—	110	—		
	下降時間 Fall Time	tf			—	200	—		
	ターンオフ遅延時間 Turn-off Delay Time	td(off)			—	500	—		
FWD	順電圧 Peak Forward Voltage		VF	If= 200A,VGE=0V (chip level)	TJ=25℃	—	2.00	2.60	V
					TJ=125℃	—	1.98	—	
					TJ=150℃	—	1.95	—	
逆回復時間 Reverse Recovery Time		trr	VCC= 600V LS=38nH If= 200A Inductive Load Rg= 3.6Ω VGE= ±15V Tj= 150℃		—	200	—	ns	
内部配線抵抗 Internal Lead Resistance			RCC+EE'	主端子—チップ間 / 1素子 Main Terminal - Chip / Per 1 Arm		—	—	1	mΩ
内部インダクタンス Stray Inductance			LSCE	メイン端子3－2間 Main Terminal3 - Main Terminal2		—	30	—	nH

□ 熱 的 特 性 : **THERMAL CHARACTERISTICS**

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
熱抵抗 Thermal Resistance	I G B T	Junction to Case Per 1 Arm (Tc測定点:チップ直下)	—	—	0.13	°C/W
	F W D		—	—	0.21	
接触熱抵抗 Thermal Resistance	I G B T	Case to heatsink Per 1 Arm Paste=1W/(m ² °C)	—	0.05	—	
	F W D		—	0.10	—	

□ 特性図 : CHARACTERISTICS CURVES

Fig.1- Output Characteristics (Typical)

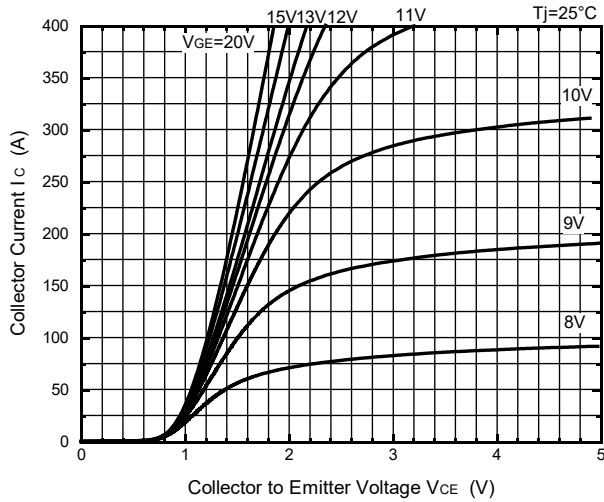


Fig.2- Saturation Voltage Characteristics (Typical)

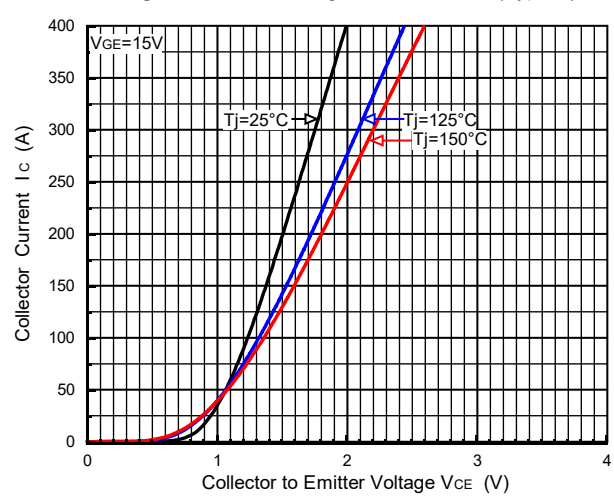


Fig.3- Transfer Characteristics (Typical)

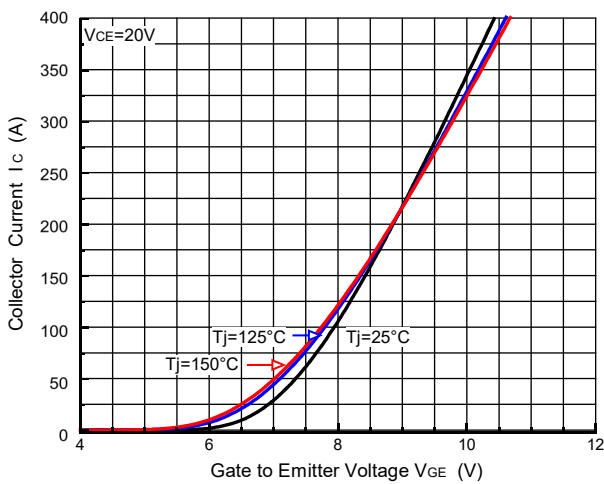


Fig.4- Gate Charge vs. Collector to Emitter Voltage (Typical)

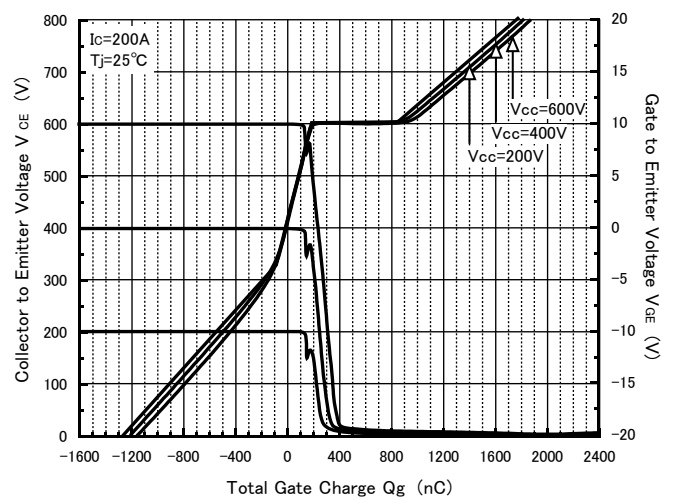


Fig.5- Collector Current vs. Switching Time

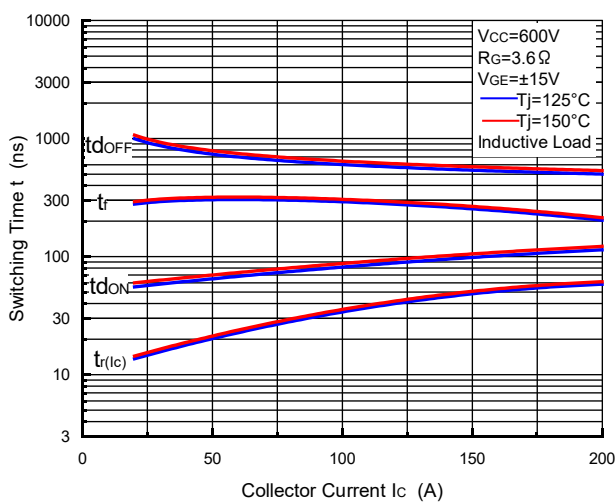
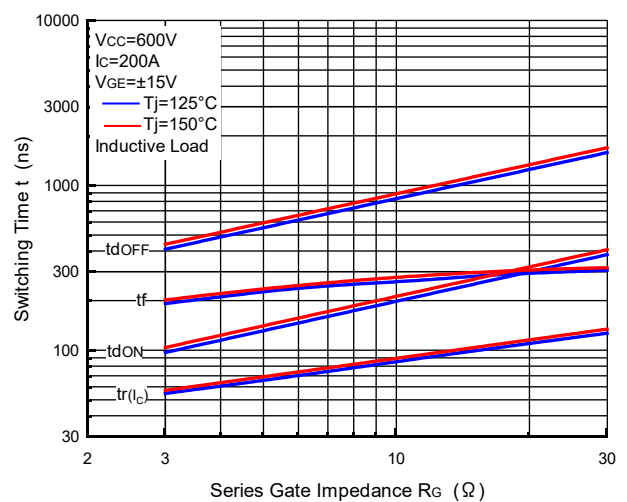


Fig.6- Series Gate Impedance vs. Switching Time



□ 特性図 : **CHARACTERISTICS CURVES**

Fig.7- Collector Current vs. Switching Loss

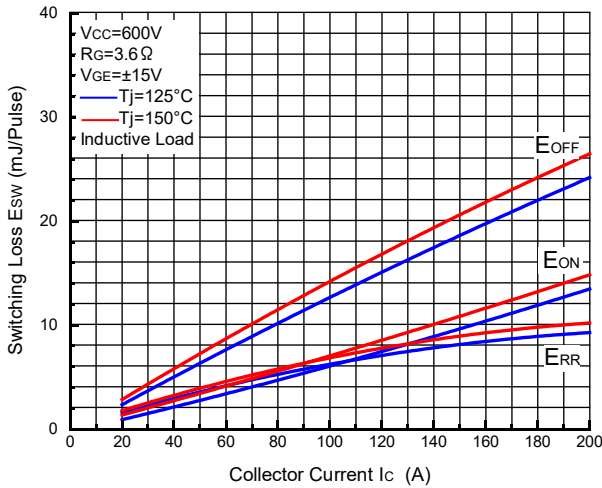


Fig.8- Series Gate Impedance vs. Switching Loss

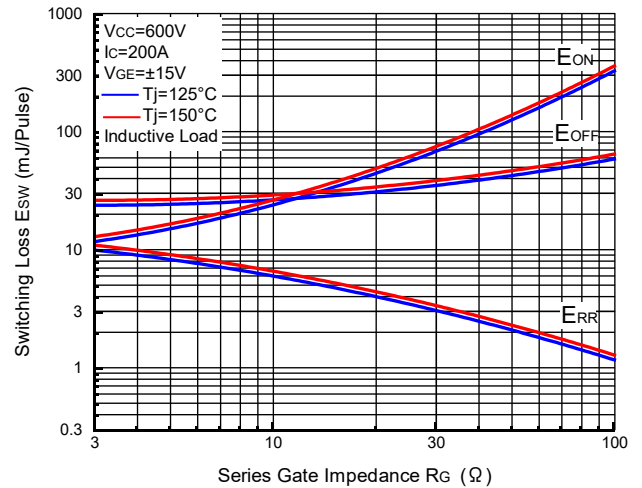


Fig.9- Forward Characteristics of FWD (Typical)

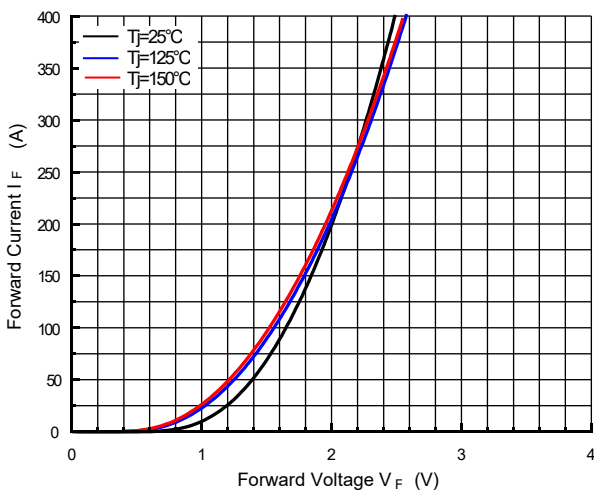


Fig.10- Reverse Recovery Characteristics of FWD & Inverse Diode (Typical)

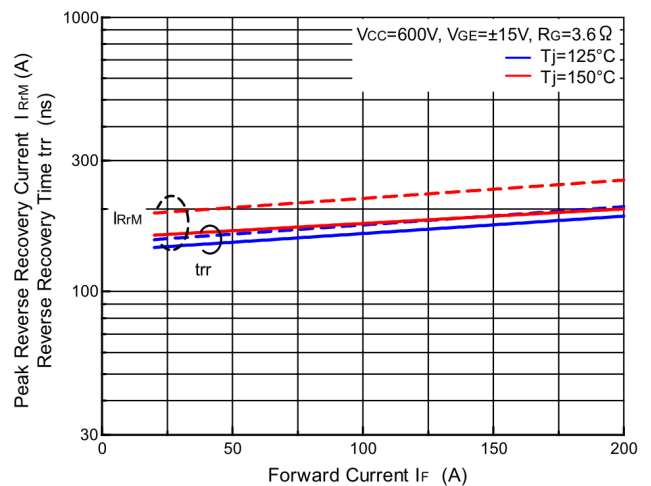


Fig.11- Reverse Bias Safe Operating Area

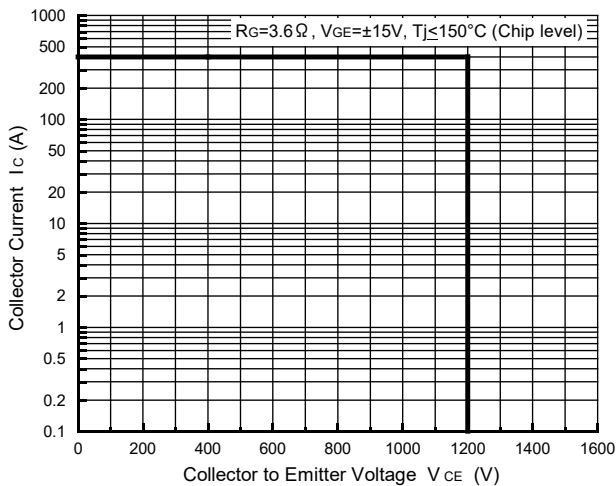
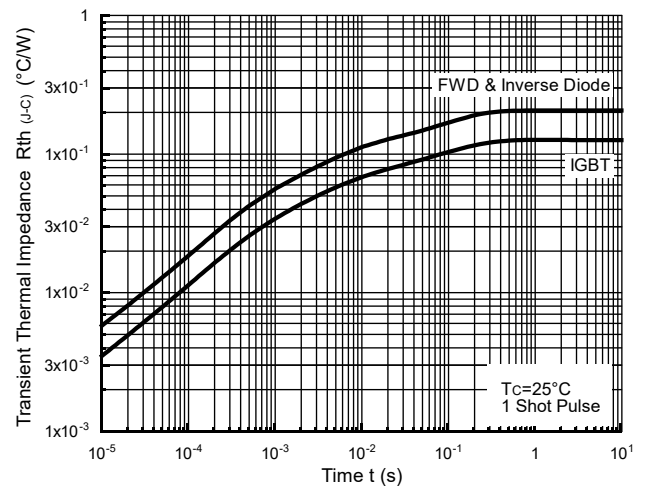


Fig.12- Transient Thermal Impedance



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